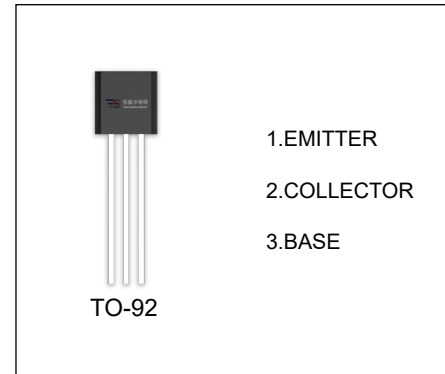


TSC1417 TRANSISTOR (NPN)

FEATURES

- General Purpose Switching and Amplification.



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
TSC1417	TO-92	Bulk	1000pcs/Bag
TSC1417-TA	TO-92	Tape	2000pcs/Box

MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	20	V
V_{CEO}	Collector-Emitter Voltage	15	V
V_{EBO}	Emitter-Base Voltage	3	V
I_C	Collector Current	30	mA
P_C	Collector Power Dissipation	625	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	200	$^{\circ}\text{C}/\text{W}$
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	$^{\circ}\text{C}$

$T_a=25\text{ }^{\circ}\text{C}$ unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=0.1\text{mA}, I_E=0$	20			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}, I_B=0$	15			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=0.1\text{mA}, I_C=0$	3			V
Collector cut-off current	I_{CBO}	$V_{CB}=10\text{V}, I_E=0$			1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=2\text{V}, I_C=0$			1	μA
DC current gain	h_{FE}	$V_{CE}=6\text{V}, I_C=1\text{mA}$	29		270	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=10\text{mA}, I_B=1\text{mA}$			0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=10\text{mA}, I_B=1\text{mA}$			1.42	V
Transition frequency	f_T	$V_{CE}=6\text{V}, I_C=1\text{mA}$		300		MHz

CLASSIFICATION OF h_{FE}

RANK	D	E	F	G	H	I	J
RANGE	29-45	39-60	54-80	72-108	97-146	132-198	180-270